SYNERGY POLYTECHNIC, BBSR

The Lesson Plan

Descipline:EE	Semester:4th	Name of the Teaching Faculty: Saswati sanghamitra Pradhan
Subject: Analog Electronics	No of Days/per week	
and Op-amp	class allotted:4	Semester from Date: 16/1/24 to Date: 26/4/24 No of Weeks: 15
Week	Class Day	Theory/Practical Topics
1		1.1)P-N Junction Diode
1st		1 .2) Working of Diode
		1 .3) V-I characteristic of PN junction Diode.
	1st	1.4) DC load line
	130	Important terms such as Ideal Diode, Knee voltage 1.6
		Junctions break down.
		1.6.1 Zener breakdown
	and	1.6.1 Zener breakdown 1.6.2 Avalanche breakdown
	2nd 3rd	
	4th	1 . 7 P-N Diode clipping Circuit.
	5th	1.8P-N Diode clamping Circuit
	1st 2nd	2 . 1 Thermistors, Sensors & barretters 2 . 2 Zener Diode, 2 . 3 Tunnel Diode, 2 . 4 PIN Diode
	3rd	Classification of rectifiers
	310	
2nd		Analysis of half wave
		1)DC output current and voltage
	4th	2)RMS output current and voltage
	5th	Problem
		3.2.3 Rectifier efficiency
1		3.2.4 Ripple factor
	1st	3.2.5 Regulation
		3.2.6 Transformer utilization factor
	2nd	3.2.7 Peak inverse voltage
		Analysis of full wave centre tapped and Bridge rectifiers 3.2.1 DC
2-4	_	output current and voltage
3rd		3.2.2 RMS output current and voltage
	3rd	3.2.3 Rectifier efficiency
		3.2.4 Ripple factor 3.2.5 Regulation
	1	3.2.5 Regulation
		3.2.6 Transformer utilization factor
	4th	3.2.7 Peak inverse voltage
	5th	Problem
		3.3 Filters:
		3.3.1 Shunt capacitor filter
	1st	
4th	2nd	3.3.2 Choke input filter
		3.3.3 π filter
	4th	4.1 Principle of Bipolar junction transistor
	5th	Problem
5th		4.2 Different modes of operation of transistor
		4.3 Current components in a transistor
		4.4 Transistor as an amplifier
	4th	4.5 Transistor circuit configuration & its characteristics
	5th	Problem

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Descipline:EE	Semester:	Name of the Teaching Faculty:Saswati sanghamitra Pradhan
Subject:Analog Electronics and Op-amp	No of Days/per week class allotted:4	Semester from Date: 16 01 2024 to Date: 26 04 200 No of Weeks: 15
Week	Class Day	Theory/Practical Topics
	1st	4.5.1 CB Configuration
	2nd	4.5.2 CE Configuration
6th	3rd	4.5.3 CC Configuration
	4th	5.1 Transistor biasing
	5th	Problem
	1st	5.2 Stabilization 5.3 Stability factor
	2nd	5.4 Different method of Transistors Biasing , 5.4.1 Base resistor method
7th	3rd	5.4.2 Collector to base bias
	4th	5.4.3 Self bias or voltage divider method
	5th	Problem
	1st	6.1 Practical circuit of transistor amplifier
8th	2nd	6.2 DC load line and DC equivalent circuit
	3rd	6.3 AC load line and AC equivalent circuit
	4th	6.4 Calculation of gain
	5th	Problem
9th	1st	6.5 Phase reversal
	2nd	6.6 H-parameters of transistors
	3rd	6.7 Simplified H-parameters of transistors
	4th	6.8 Generalised approximate model
	5th	Problem
10th	1st	6.9 Analysis of CB, CE, CC amplifier using generalised approximate model
		6.10 Multi stage transistor amplifier
	3rd	6.10.1 R.C. coupled amplifier 6.10.2 Transformer coupled amplifier
		6.11 Feed back in amplifier
		6.11.1 General theory of feed back
		6.11.2 Negative feedback circuit
	5th	Problem

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Principal 16/1/24

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Descipline:EE	Semester:	Name of the Teaching Faculty: Saswati sanghamitra Pradhan	
Subject:Analog Electronics	No of Days/per week	Semester from Date: 16 01 2024 to Date: 26 04 24 No of Weeks: 15	
and Op-amp	class allotted:4	10/0//2007	
Week	Class Day	Theory/Practical Topics	
		6.12 Power amplifier and its classification	
11 th	1st	6.12.1 Difference between voltage amplifier and power amplifier	
	2nd	6.12.2 Transformer coupled class A power amplifier	
	3rd	6.12.3 Class A push – pull amplifier	
	4th	6.12.4 Class B push – pull amplifier	
	5th	Problem	
		6.13 Oscillators	
		6.13.1 Types of oscillators	
	1st	6.13.2 Essentials of transistor oscillator	
12th		6.13.3 Principle of operation of tuned collector, Hartley, colpitt, phase shift, weint	oridge
	2nd	oscillator (no mathematical derivations)	
		7.1 Classification of FET	
	3rd	7.2 Advantages of FET over BJT	
	4th	7.3 Principle of operation of BJT	
	5th	Problem	
		7.4 FET parameters (no mathematical derivation)	4.1 DC
		drain resistance	2 AC
		drain resistance 7.4.	3
	1st	Trans-conductance	
13th	2nd	7.5 Biasing of FET	
	3rd	8.1 General circuit simple of OP-AMP and IC – CA – 741 OP AMP	
		8.2 Operational amplifier stages	8.3
	4th	Equivalent circuit of operational amplifier	
	5th	Problem	
14th		8.4 Open loop OP-AMP configuration	8.5
	1st	OPAMP with fed back	
		8.6 Inverting OP-AMP	8.7
		Non inverting OP-AMP	
		8.8 Voltage follower & buffer	
		8.9 Differential amplifier	
		8.9.1 Adder or summing amplifier	
		8.9.2 Sub tractor	
		8.9.3 Integrator	
	l l	8.9.4 Differentiator	
	4th	8.9.5 Comparator	
	5th	frolden	
15th	1st	Revision	
	2nd	Revision	
	3rd F	Revision	
		Revision	
	5th	Problem	

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